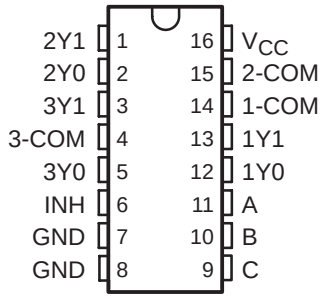
- **Controlled Baseline**
  - **One Assembly/Test Site, One Fabrication Site**
- **Extended Temperature Performance of −40°C to 105°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree†**
- **2-V to 5.5-V V_{CC} Operation**
- **Supports Mixed-Mode Voltage Operation on All Ports**
- **High On-Off Output-Voltage Ratio**
- **Low Crosstalk Between Switches**
- **Individual Switch Controls**
- **Extremely Low Input Current**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **ESD Protection Exceeds JESD 22**
  - **2000-V Human-Body Model (A114-A)**
  - **200-V Machine Model (A115-A)**
  - **1000-V Charged-Device Model (C101)**

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

D OR PW PACKAGE
(TOP VIEW)



description/ordering information

This triple 2-channel CMOS analog multiplexer/demultiplexer is designed for 2-V to 5.5-V V_{CC} operation.

The SN74LV4053A handles both analog and digital signals. Each channel permits signals with amplitudes up to 5.5 V (peak) to be transmitted in either direction.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

ORDERING INFORMATION

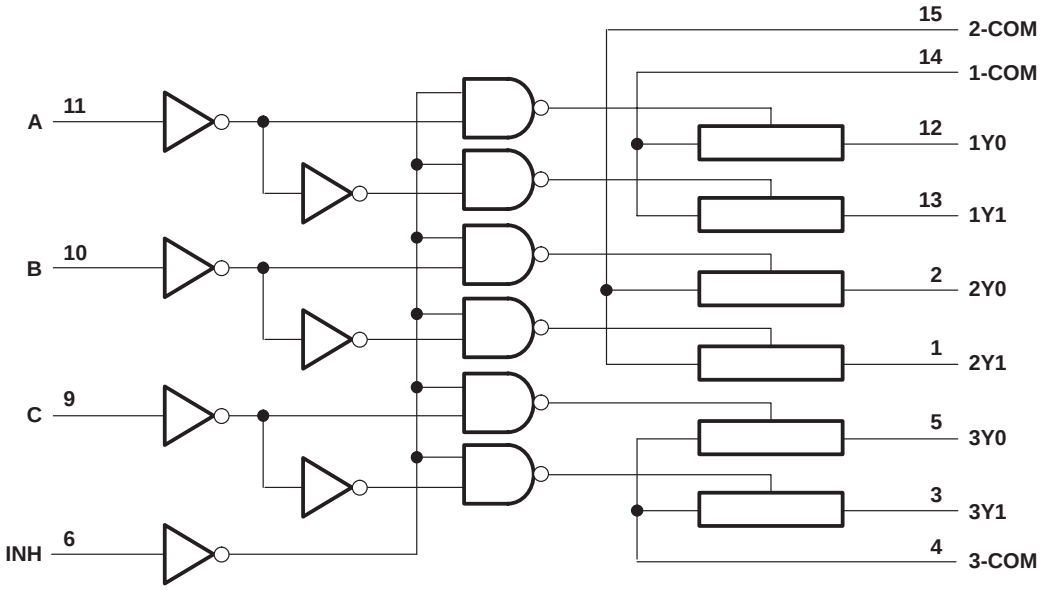
T_A	PACKAGE‡		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−40°C to 105°C	SOIC − D	Tape and reel	SN74LV4053ATDREP	LV4053ATEP
	TSSOP − PW	Tape and reel	SN74LV4053ATPWREP	L4053EP

‡ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

INPUTS				ON CHANNELS
INH	C	B	A	
L	L	L	L	1Y0, 2Y0, 3Y0
L	L	L	H	1Y1, 2Y0, 3Y0
L	L	H	L	1Y0, 2Y1, 3Y0
L	L	H	H	1Y1, 2Y1, 3Y0
L	H	L	L	1Y0, 2Y0, 3Y1
L	H	L	H	1Y1, 2Y0, 3Y1
L	H	H	L	1Y0, 2Y1, 3Y1
L	H	H	H	1Y1, 2Y1, 3Y1
H	X	X	X	None

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . −0.5 V to 7.0 V
Input voltage range, V_I (see Note 1) . . . . . −0.5 V to 7.0 V
Switch I/O voltage range, V_{IO} (see Notes 1 and 2) . . . . . −0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} (V_I < 0) . . . . . −20 mA
I/O diode current, I_{IOK} (V_{IO} < 0) . . . . . −50 mA
Switch through current, I_T (V_{IO} = 0 to V_{CC}) . . . . . ±25 mA
Continuous current through V_{CC} or GND . . . . . ±50 mA
Package thermal impedance, θ_{JA} (see Note 3): D package . . . . . 73°C/W
PW package . . . . . 108°C/W
Storage temperature range, T_{stg} . . . . . −65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2‡	5.5	V
V_{IH}	High-level input voltage, control inputs	V_{CC} = 2 V	1.5		V
		V_{CC} = 2.3 V to 2.7 V	$V_{CC} \times 0.7$		
		V_{CC} = 3 V to 3.6 V	$V_{CC} \times 0.7$		
		V_{CC} = 4.5 V to 5.5 V	$V_{CC} \times 0.7$		
V_{IL}	Low-level input voltage, control inputs	V_{CC} = 2 V		0.5	V
		V_{CC} = 2.3 V to 2.7 V		$V_{CC} \times 0.3$	
		V_{CC} = 3 V to 3.6 V		$V_{CC} \times 0.3$	
		V_{CC} = 4.5 V to 5.5 V		$V_{CC} \times 0.3$	
V_I	Control input voltage		0	5.5	V
V_{IO}	Input/output voltage		0	V_{CC}	V
$\Delta t/\Delta v$	Input transition rise or fall rate	V_{CC} = 2.3 V to 2.7 V		200	ns/V
		V_{CC} = 3 V to 3.6 V		100	
		V_{CC} = 4.5 V to 5.5 V		20	
T_A	Operating free-air temperature		−40	105	°C

‡ With supply voltages at or near 2 V, the analog switch on-state resistance becomes very nonlinear. It is recommended that only digital signals be transmitted at these low supply voltages.

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	T_A = 25°C			MIN	MAX	UNIT
				MIN	TYP	MAX			
r_{on}	On-state switch resistance	I_T = 2 mA, V_I = V_{CC} or GND, V_{INH} = V_{IL}, (see Figure 1)	2.3 V		41	180		225	Ω
			3 V		30	150		190	
			4.5 V		23	75		100	
$r_{on(p)}$	Peak on-state resistance	I_T = 2 mA, V_I = V_{CC} to GND, V_{INH} = V_{IL}	2.3 V		139	500		600	Ω
			3 V		63	180		225	
			4.5 V		35	100		125	
Δr_{on}	Difference in on-state resistance between switches	I_T = 2 mA, V_I = V_{CC} to GND, V_{INH} = V_{IL}	2.3 V		2	30		40	Ω
			3 V		1.6	20		30	
			4.5 V		1.3	15		20	
I_I	Control input current	V_I = 5.5 V or GND	0 to 5.5 V			±0.1		±1	µA
$I_{S(off)}$	Off-state switch leakage current	V_I = V_{CC} and V_O = GND, or V_I = GND and V_O = V_{CC}, V_{INH} = V_{IH}, (see Figure 2)	5.5 V			±0.1		±1	µA
$I_{S(on)}$	On-state switch leakage current	V_I = V_{CC} or GND, V_{INH} = V_{IH} (see Figure 3)	5.5 V			±0.1		±1	µA
I_{CC}	Supply current	V_I = V_{CC} or GND	5.5 V					20	µA
C_{IC}	Control input capacitance				2				pF
C_{IS}	Common terminal capacitance				8.2				pF
C_{OS}	Switch terminal capacitance				5.6				pF
C_F	Feedthrough capacitance				0.5				pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V ± 0.2 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	T_A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF, (see Figure 4)		2.5	10		16	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF, (see Figure 5)		7.6	18		23	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF, (see Figure 5)		7.7	18		23	ns
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF, (see Figure 4)		4.4	12		18	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF, (see Figure 5)		8.8	28		35	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF, (see Figure 5)		11.7	28		35	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	T_A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF, (see Figure 4)		1.6	6		10	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF, (see Figure 5)		5.3	12		15	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF, (see Figure 5)		6.1	12		15	ns
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF, (see Figure 4)		2.9	9		12	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF, (see Figure 5)		6.1	20		25	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF, (see Figure 5)		8.9	20		25	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	T_A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF, (see Figure 4)		0.9	4		7	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF, (see Figure 5)		3.8	8		10	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF, (see Figure 5)		4.6	8		10	ns
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF, (see Figure 4)		1.8	6		8	ns
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF, (see Figure 5)		4.3	14		18	ns
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF, (see Figure 5)		6.3	14		18	ns

analog switch characteristics

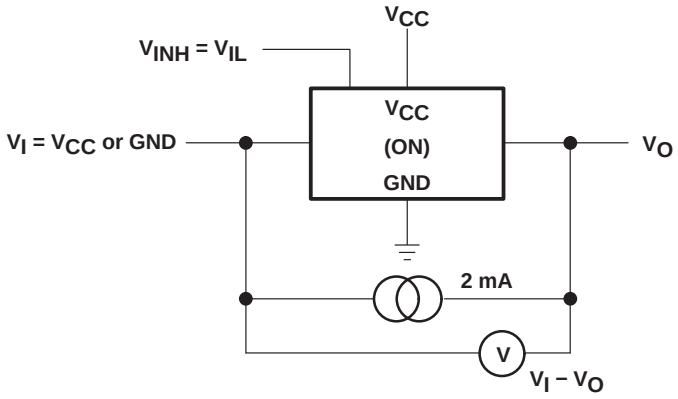
PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		V_{CC}	T_A = 25°C MIN	TYP	MAX	UNIT
Frequency response (switch on)	COM or Yn	Yn or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) (see Note 5 and Figure 6)		2.3 V		30		MHz
					3 V		35		
					4.5 V		50		
Crosstalk (between any switches)	COM or Yn	Yn or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) (see Note 6 and Figure 7)		2.3 V		−45		dB
					3 V		−45		
					4.5 V		−45		
Crosstalk (control input to signal output)	INH	COM or Yn	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (square wave) (see Figure 8)		2.3 V		20		mV
					3 V		35		
					4.5 V		65		
Feedthrough attenuation (switch off)	COM or Yn	Yn or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (see Note 6 and Figure 9)		2.3 V		−45		dB
					3 V		−45		
					4.5 V		−45		
Sine-wave distortion	COM or Yn	Yn or COM	C_L = 50 pF, R_L = 10 kΩ, f_{in} = 1 kHz (sine wave) (see Figure 10)	V_I = 2 V_{p-p}	2.3 V		0.1		%
				V_I = 2.5 V_{p-p}	3 V		0.1		
				V_I = 4 V_{p-p}	4.5 V		0.1		

NOTES: 5. Adjust f_{in} voltage to obtain 0-dBm output. Increase f_{in} frequency until dB meter reads −3 dB.
6. Adjust f_{in} voltage to obtain 0-dBm input.

operating characteristics, V_{CC} = 3.3 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance	C_L = 50 pF,	f = 10 MHz	5.3	pF

PARAMETER MEASUREMENT INFORMATION



$$r_{on} = \frac{V_I - V_O}{2 \times 10^{-3}}\ \Omega$$

Figure 1. On-State Resistance Test Circuit

PARAMETER MEASUREMENT INFORMATION

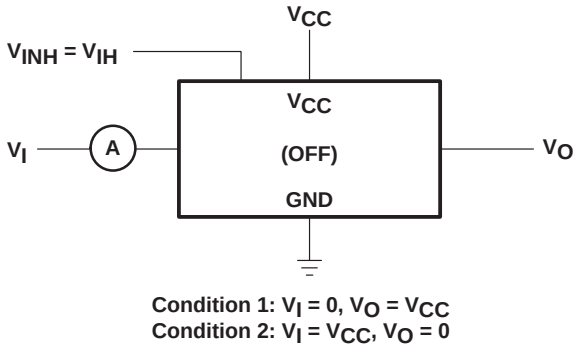


Figure 2. Off-State Switch Leakage-Current Test Circuit

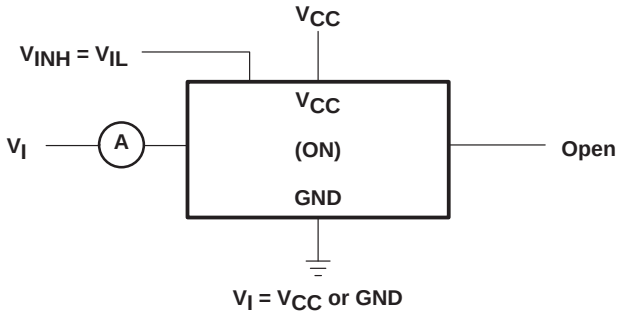


Figure 3. On-State Switch Leakage-Current Test Circuit

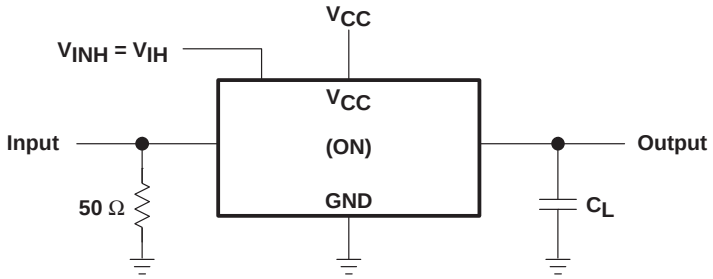
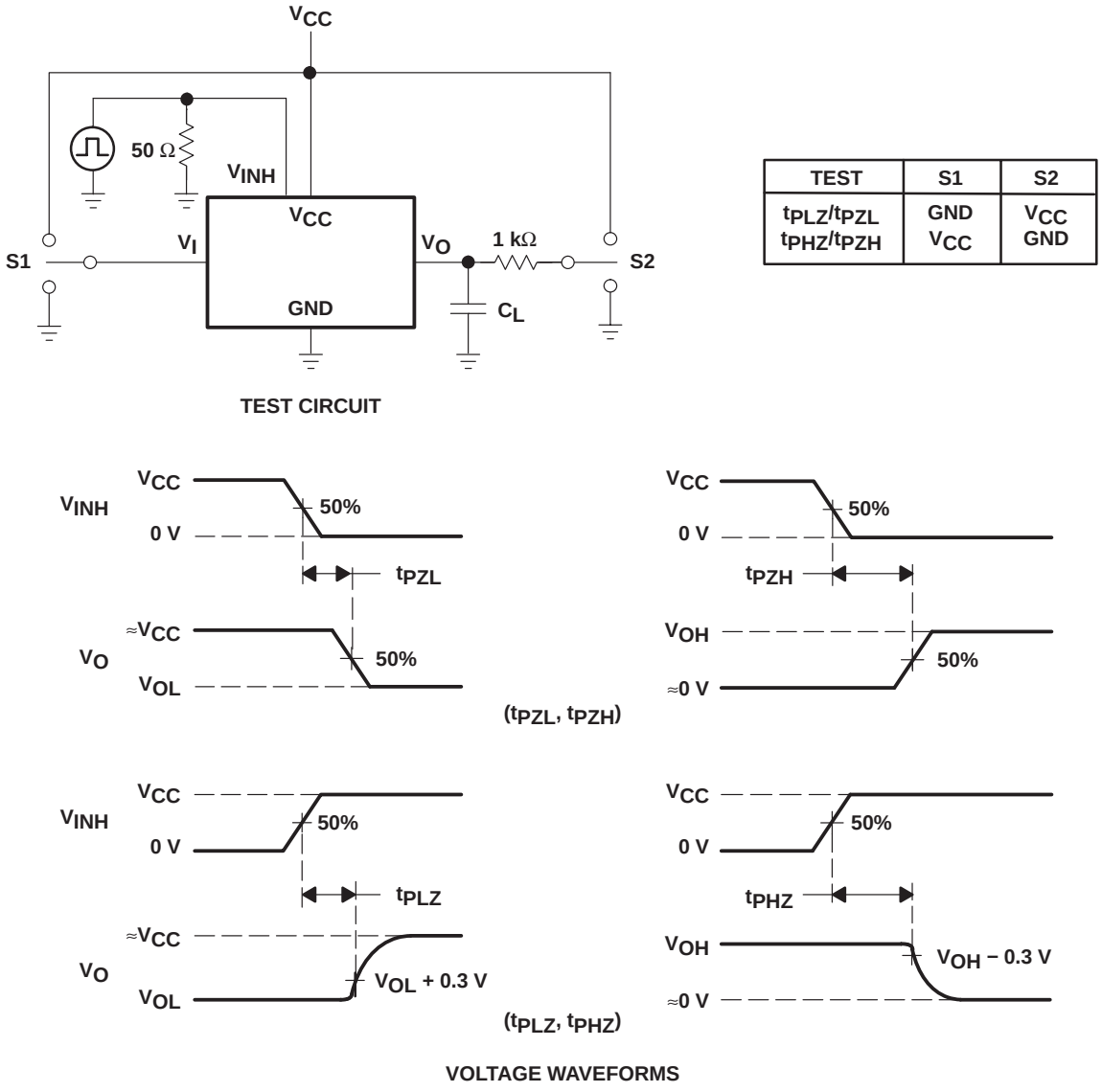


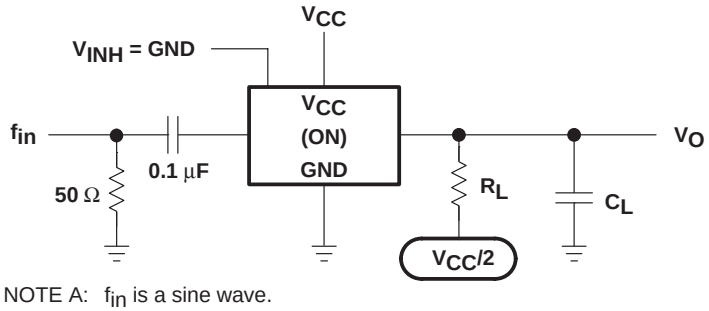
Figure 4. Propagation Delay Time, Signal Input to Signal Output

PARAMETER MEASUREMENT INFORMATION



TEST	S1	S2
t_{PLZ}/t_{PZL} t_{PHZ}/t_{PZH}	GND V_{CC}	V_{CC} GND

Figure 5. Switching Time (t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}), Control to Signal Output



NOTE A: f_{in} is a sine wave.

Figure 6. Frequency Response (Switch On)

PARAMETER MEASUREMENT INFORMATION

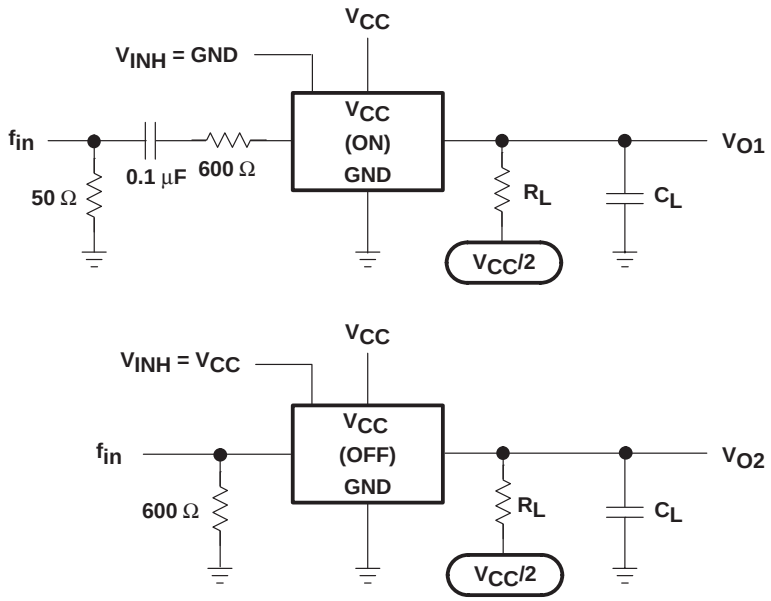


Figure 7. Crosstalk Between Any Two Switches

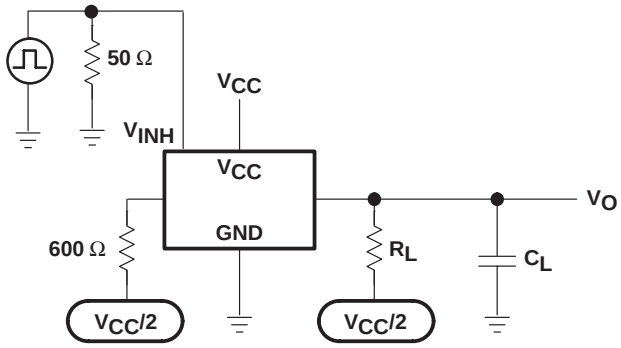


Figure 8. Crosstalk Between Control Input and Switch Output

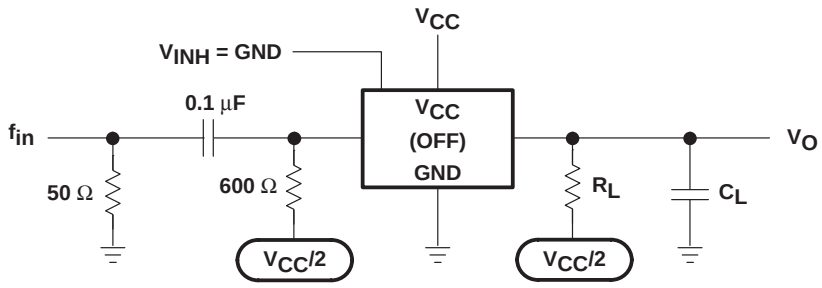


Figure 9. Feedthrough Attenuation (Switch Off)

PARAMETER MEASUREMENT INFORMATION

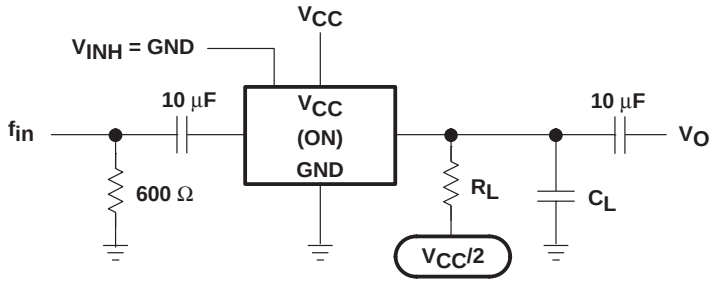


Figure 10. Sine-Wave Distortion

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LV4053ATPWREP	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	L4053EP
SN74LV4053ATPWREP.A	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	L4053EP
V62/03666-01XE	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	L4053EP

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

OTHER QUALIFIED VERSIONS OF SN74LV4053A-EP :

- Catalog : SN74LV4053A

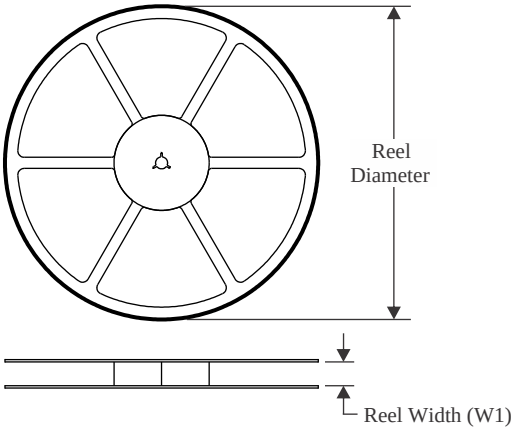
- Automotive : SN74LV4053A-Q1

NOTE: Qualified Version Definitions:

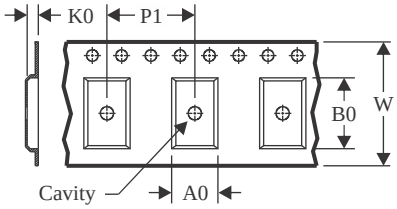
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

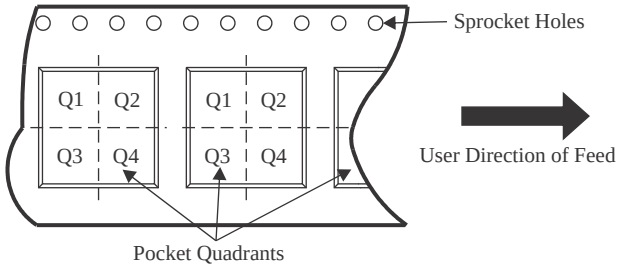


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

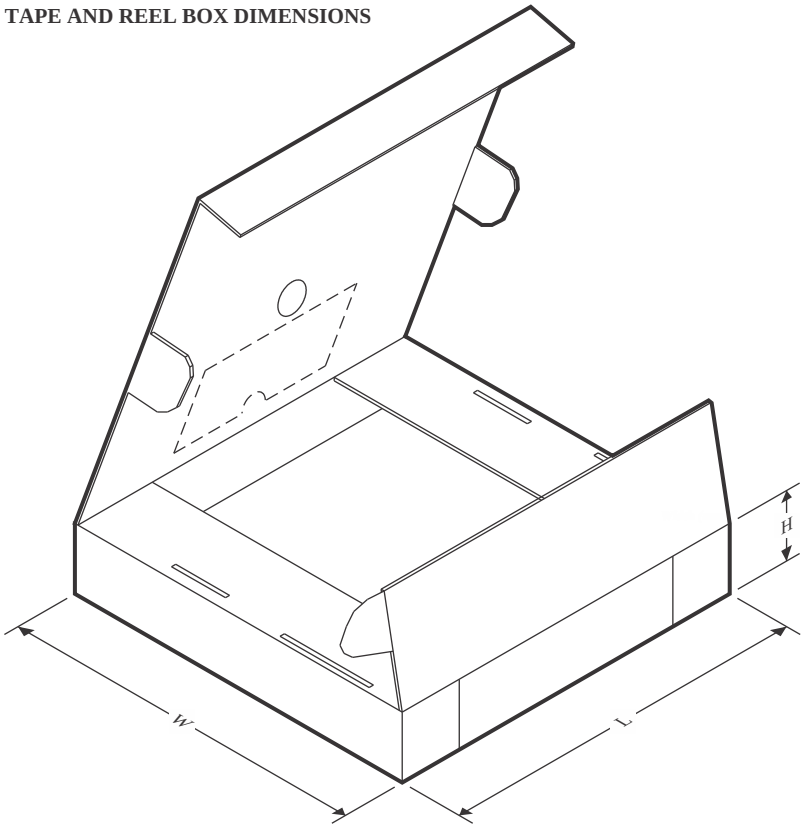
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV4053ATPWREP	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

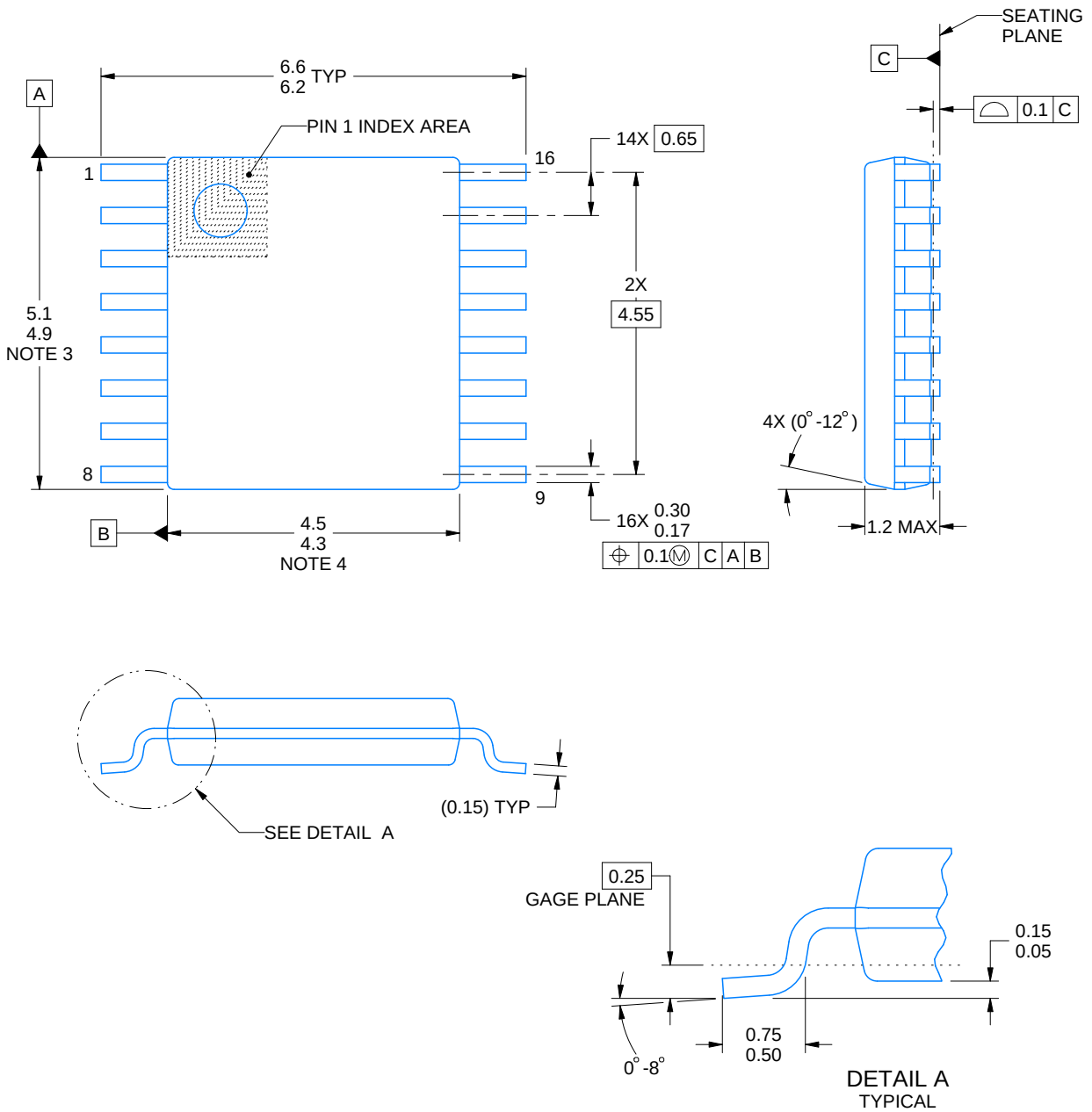
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV4053ATPWREP	TSSOP	PW	16	2000	353.0	353.0	32.0

PACKAGE OUTLINE

PW0016A

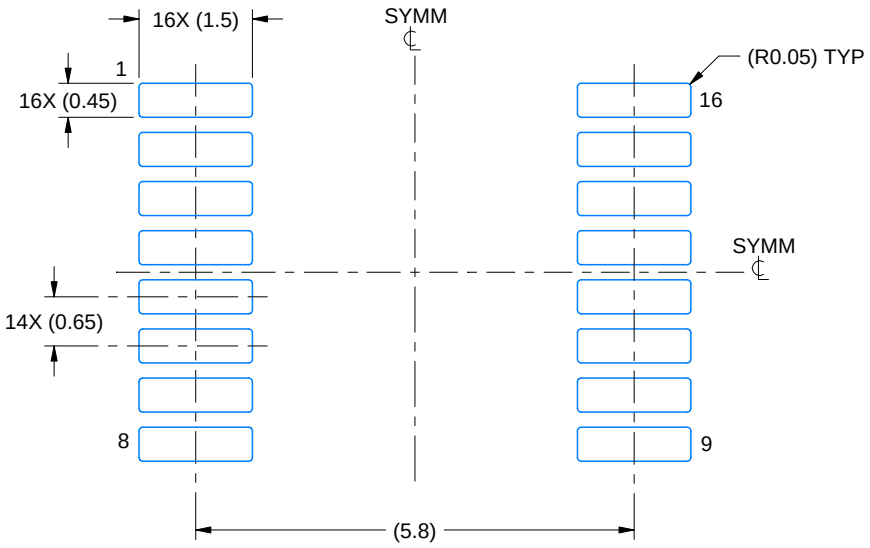
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



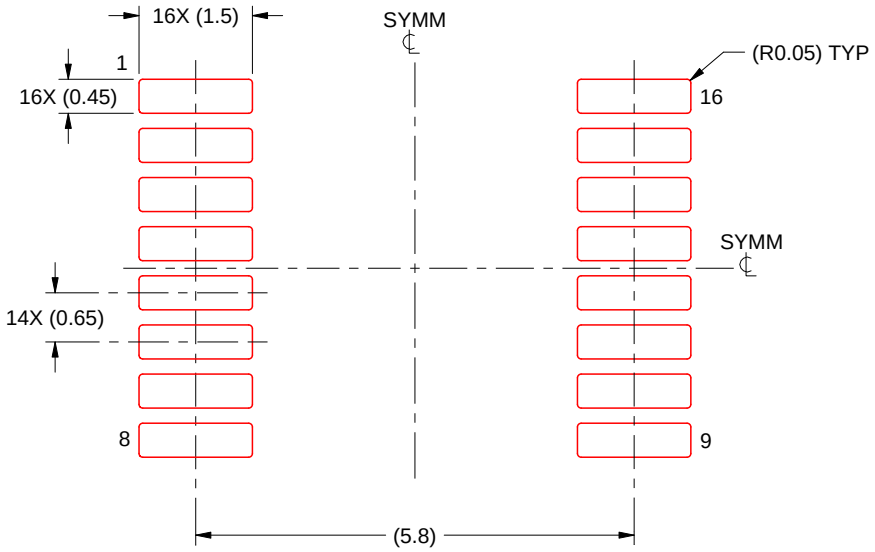
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK DETAILS

4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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